

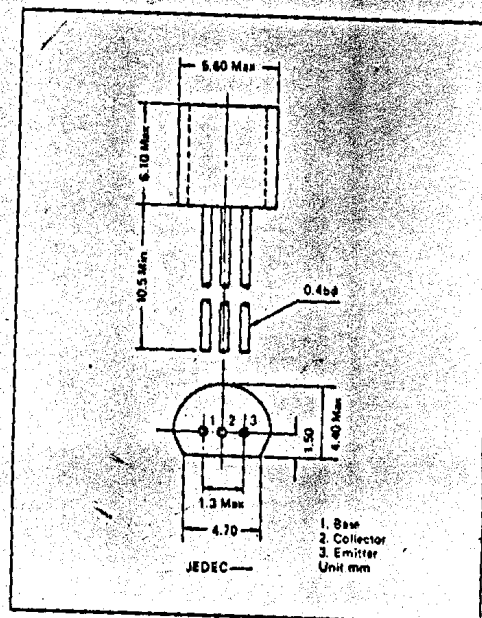
# 2SC1363, 1364

Silicon NPN APM Transistor

- 汎用増幅, 200mA, 320mW
- Complementary to 2SC1363: 2SA677  
2SC1364: 2SA678
- Family 2SC1633, 2SC1634

絶対最大定格 Absolute Maximum Ratings  $T_a = 25^\circ\text{C}$

Characteristics	Symbol	2SC1363	2SC1364
Collector-to-Base Voltage	$V_{CB0}$	25V	50V
Collector-to-Emitter Voltage	$V_{CE0}$	25V	50V
Emitter-to-Base Voltage	$V_{EB0}$	6V	
Collector Current	$I_C$	200 mA	
Base Current	$I_B$	50 mA	
Collector Power Dissipation	$P_G$	320 mW	
Junction Temperature	$T_J$	120°C	
Storage Temperature	$T_{stg}$	-30~+150°C	



電気的特性 Electrical Characteristics  $T_a = 25^\circ\text{C}$

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector Cutoff Current	$I_{CB0}$	$V_{CB} = 25V, I_E = 0$				
Emitter Cutoff Current	$I_{EB0}$	$V_{EB} = 6V, I_C = 0$			0.2	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE} = 3V, I_C = 1\text{ mA}$	82		690	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 50\text{ mA}, I_B = 10\text{ mA}$		0.10	0.30	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$			0.82	1.20	V
Small Signal Current Gain	$ h_{fe} $	$V_{CE} = 6V, I_E = -2\text{ mA}, f = 100\text{ MHz}$		1.0	3.0	dB
Output Capacitance	$C_{ob}$	$V_{CB} = 6V, I_E = 0, f = 1\text{ MHz}$		4.5	7.0	pF
Collector-to-Base Time Constant	$C_c \cdot f_{bb'}$	$V_{CB} = 6V, I_E = -2\text{ mA}, f = 1.59\text{ MHz}$		300	600	ps

規格細分 Classifications

Rank	$h_{FE} (I_C = 1\text{ mA}, V_{CE} = 3V)$
5	82-175
6	129-276
7	204-442
7	326-609